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Thermophysical Model for the Infrared Emissivity of Metals: Application to Nickel

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JACOBS SCHOOL OF ENGINEERING Mechanical and Aerospace Engineering



Shaping the Future of Aerospace

## In this presentation

What?

- model derived for temperature-dependent infrared emissivity of metals
- applied to nickel

#### How?

- generalizing a well-known model for carrier transport
  - 1. derive anomalous carrier transport model
  - 2. determine functional form for the temperature-dependent parameters

Why?

 knowledge of a material's emissivity is important for a wide range of design applications: signal suppressing metamaterials [1], engine componentry [2], non-contact thermometry [3], etc.

<sup>[1]</sup> H. Kocer, et al., "Reduced near-infrared absorption using ultra-thin lossy metals in Fabry-Perot cavities," Sci. Rep., Vol. 5, 2015, p. 8157.

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<sup>[3]</sup> K.-H. Weng, C.-D. Wen, "Effect of oxidation on aluminum alloys temperature prediction using multispectral radiation thermometry," Int. J. Heat Mass Tran., Vol. 54, No. 23, 2011, pp. 4834–4843.

#### Simple model for free-carrier transport

Drude(-Langevin) transport of a single charge carrier

- predicts response of "good" free-electron metals (*e.g.*, monovalent noble metals) [4]
- classically, a microscopic equation of motion in the carrier velocity [5]:

$$m^* \frac{dv(t)}{dt} + \zeta v(t) = q \mathcal{E}(t) + q \eta(t)$$
 random field fluctuations fluctuations

 leads to the complex-valued (electric) susceptibility (*i.e.*, the Fourier transform of the polarization density):

$$\chi_d(\lambda) = \frac{i\,\lambda}{2\,\pi\,c_0\,\varepsilon_0}\sigma_d(\lambda) = -\frac{\lambda^2}{2\,\pi\,c_0\,\varepsilon_0}\left(\frac{\sigma_\gamma}{i\,\lambda+\lambda_\gamma}\right)$$

[4] F. Wooten, Optical Properties of Solids, Academic Press, New York, 1972.

[5] N. Pottier, Nonequilibrium Statistical Physics: Linear Irreversible Processes, Oxford graduate texts, Oxford University Press, Oxford, 2010.

## Simple model for free-carrier transport

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- classically, a macroscopic equation of motion in the current density [5]:

$$\tau_{c} \frac{dj(t)}{dt} + j(t) = \left( \frac{n_{d} q^{2} \tau_{c}}{m^{*}} \right) (E(t))^{m}$$

macroscopic (incident) field

 leads to the complex-valued (electric) susceptibility (*i.e.*, the Fourier transform of the polarization density):

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## Applicability of the Drude model

Drude model is insufficient for explaining data produced by media that deviate substantially from the free electron model. Example: nickel.



[6] M. A. Ordal *et al.*, "Optical properties of Au, Ni, and Pb at submillimeter wavelengths," *Appl. Opt.*, Vol. 26, No. 4, 1987, pp.744–752.

## Basis for the proposed model: field relaxation with memory

• Drude-Langevin transport for a single charge carrier:

$$m^* \frac{dv(t)}{dt} + \zeta v(t) = q \mathcal{E}(t) + q \eta(t)$$

• generalized with a (temporally) nonlocal relaxation in the (spatially) local field [7] : history integral

$$\widetilde{\eta}(t) = \lim_{t_0 \downarrow -\infty} \int_{t_0}^{t} \widetilde{\mathcal{H}}(t-s) \sqrt{\frac{d\mathcal{E}(s)}{ds}} ds + \eta(t)$$
  
history kernel historical change rate

• we choose a history kernel the represents a generalization of the Markovian approximation,  $H(t) = \delta(t)$ : characteristic time of field relaxation

 $\frac{(\tau_f/t)^{\mu}}{\Gamma(1-\mu)} \longrightarrow \text{memory decay strength}$ 

#### generalized factorial function

#### Imparting temperature dependence on the model

• generalized fluctuating field leads to a fractional differential transport model:

$$\tau_c \, \frac{dj(t)}{dt} + j(t) = \sigma_\gamma \left( E(t) + \tau_f^\mu \, \frac{d^\mu E(t)}{dt^\mu} \right)$$

• temperature-dependence modeled in terms of its effect on the collisional rate:

$$\sigma_{\gamma}(T) = \frac{n_d q^2}{m^*} \tau_c(T)$$

 to account for the possibility of anomalous carrier dynamics in regimes distinct from those of the bulk Drude behavior, a (potentially temperature-dependent) time constant scaling law is defined:

$$\tau_a(T) = \alpha(T) \tau_c(T)$$
$$\Rightarrow \sigma_a(T) = \frac{n_d q^2}{m^*} \alpha(T) \tau_c(T)$$

## Independent contributions to the current density

• resulting temperature-dependent macroscopic equations

$$\tau_{c}(T) \frac{dj_{d}(t)}{dt} + j_{d}(t) = \frac{n_{d} e^{2}}{m^{*}} \tau_{c}(T) E(t) \qquad \longleftarrow \text{Drude component}$$
  
$$\tau_{a}(T) \frac{dj_{a}(t)}{dt} + j_{a}(t) = \frac{n_{d} e^{2}}{m^{*}} \tau_{a}(T) \tau_{f}^{\mu} \frac{d^{\mu} E(t)}{dt^{\mu}} \qquad \longleftarrow \text{ anomalous component}$$

• total current density is the sum of the Drude component and the anomalous component, with the implied physical constraints:

$$\frac{\sigma_a(T)}{\lambda_a(T)} = \frac{\sigma_\gamma(T)}{\lambda_\gamma(T)} = \text{constant}$$

• note: characteristic wavelengths are computed from time constants  $\lambda(T) = 2\pi c_0/\tau(T)$ 

## Fidelity of the proposed model

Applying the proposed model to a given set of data (*i.e.*, at a single temperature) leads to an improvement over the Drude model.



#### Temperature-dependent photonic conductivity

• temperature-dependent resistivity (inverse conductivity) is predicted, *e.g.*, by the solution to the Boltzmann equation in the relaxation time approximation [5]:

$$\rho_{\gamma}(T) = \rho_r + \rho_T(T) \propto \tau_c(T)^{-1}$$

- temperature-independent residual resistivity  $\rho_r$  is due to concomitant lattice imperfections (lattice errors, impurities, etc.)
- temperature-dependent resistivity can be captured over a limited temperature range with the power law

$$\rho_T(T) = \rho_{\rm ref} \left( T / T_{\rm ref} \right)^k$$

## Procedural regression of parameters from experimental data

- 7 primary data sets were used: {4, 305, 583, 722, 1083, 1238, 1403} K [8-10]
- 1 auxiliary data set 294 K [6]
- parameter regression
  - 1. temperature-independent parameters fixed with low-temp data
  - 2. resulting structure regressed at each temperature
  - 3. functional relation for  $\rho_{\nu}(T)$  obtained from these values
- result: temperature- and wavelength-dependent complex-valued susceptibility model

[8] D. W. Lynch et al., "Infrared and visible optical properties of single crystal Ni at 4K," Solid State Commun., Vol. 9, No. 24, 1971, pp.2195–2199.

[9] D. K. Edwards, N. Bayard De Volo, "Useful Approximations for the Spectral and Total Emissivity of Smooth Bare Metals," Advances in Thermophysical Properties at Extreme Temperatures and *Pressures*, edited by S. Gratch, ASME, New York, 1965.

<sup>[10]</sup> G. W. Autio, E. Scala, "The normal spectral emissivity of isotropic and anisotropic materials," *Carbon*, Vol. 4, No. 1, 1966, pp.13–28.

## Finalizing the model

• it was found that

 $\alpha(T) \tau_c(T) \approx \text{constant}$  $\Rightarrow \lambda_a \approx \text{constant}$  $\Rightarrow \sigma_a \approx \text{constant}$ 

leading to a free-carrier susceptibility model having the form

 $\chi_{\phi}(\lambda,T) = \chi_{d}(\lambda,T) + \chi_{a}(\lambda)$ temperature-dependent / temperature-independent / anomalous component

 the complex refractive index, complex Fresnel coefficients, and radiative parameters are then computed in the usual manner

## **Comparative results**

• EBdV = Edwards and Bayard De Volo model [9]



## Prediction of auxiliary data

• 294K data = Ordal *et al.* [6]



# Concluding remarks

• power law conductivity fit in relative agreement with the literature ( $\rho_{ref}$  = 92 nohm, k = 1.60)

	51	1.20	
Nickel, Ni	69	1.64	[11]
Michigan Mih	160	0.00	

- model is realized in complex susceptibility, so we have access to
  - 1. temp.-dep. permittivity
  - 2. temp.-dep. refractive index
  - 3. temp.-dep. complex Fresnel coefficients
- can be used in more general optical and radiative frameworks (e.g., non-smooth media [12])

[11] S. Kasap, P. Capper, editors, *Springer Handbook of Electronic and Photonic Materials*, Springer, New York, 2006.

[12] K. Tang, R. O. Buckius, "A statistical model of wave scattering from random rough surfaces," Int. J. Heat Mass Tran., Vol. 44, No. 21, 2001, pp.4059–4073.

## References

- [1] H. Kocer, et al., "Reduced near-infrared absorption using ultra-thin lossy metals in Fabry-Perot cavities," Sci. Rep., Vol. 5, 2015, p. 8157.
- [2] G. Teodorescu *et al.*, "Normal emissivity of high-purity nickel at temperatures between 1440 and 1605 K," J. Phys. Chem. Solids, Vol. 69, No. 1, 2008, pp. 133–138.
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- [6] M. A. Ordal et al., "Optical properties of Au, Ni, and Pb at submillimeter wavelengths," Appl. Opt., Vol. 26, No. 4, 1987, pp.744–752.
- [7] J. Orosco, C. F. M. Coimbra, "Anomalous carrier transport model for broadband infrared absorption in metals," *Phys. Rev. B*, Vol. 98, No. 23, 2018, 235118.
- [8] D. W. Lynch *et al.*, "Infrared and visible optical properties of single crystal Ni at 4K," *Solid State Commun.*, Vol. 9, No. 24, 1971, pp.2195–2199.
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